NSN 5961-01-147-3902

Thyristor Semiconductor Device - Page 1 of 2



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Inclosure Material:
Metal
Overall Length:
1.646 inches
End Application:
Computer
Mounting Facility Quantity:
1
Internal Configuration:
Junction contact
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-48
Mounting Method:
Threaded stud
Features Provided:
Hermetically sealed case and quality assurance level tx
Overall Width Across Flats:
Between 0.544 inches and 0.563 inches
Thread Size:
0.250 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
600.0 repetitive peak reverse voltage and 720.0 nonrepetitive peak reverse voltage and 5.0 peak gate voltage
Current Rating Per Characteristic:
16.00 amperes forward current, average absolute and 150.00 amperes peak forward surge current absolute
Maximum Operating Tempurature Per Measurement Point:
125.0 degrees celsius case
Special Features:
Junction pattern arrangement: pnpn
Test Data Document:
81349-mil-prf-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Thread Series Designator:
Unf
Terminal Type And Quantity:
1 threaded stud and 2 insulated wire lead w/terminal lug
Specification Data:
81349-mil-prf-19500/108 government specification
Shelf Life:
N/a

Unit Of Measure:

NSN 5961-01-147-3902

Thyristor Semiconductor Device - Page 2 of 2



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Mil-std (military Standard):

Mil-prf-19500 spec.